

# AMOSPEC

## PLASTIC MEDIUM-POWER COPLEMENTARY SILICON TRANSISTORS

...designed for general-purpose amplifier and low speed switching applications

### FEATURES:

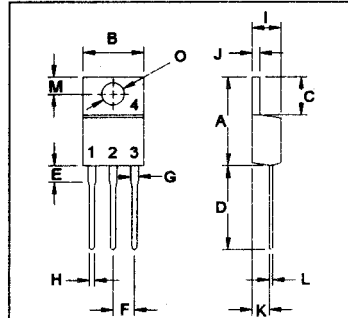
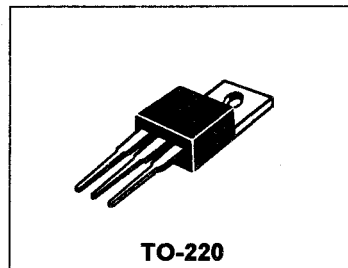
- \* Collector-Emitter Sustaining Voltage-  
 $V_{CE(SUS)}$  = 60 V (Min) - TIP120, TIP125  
 = 80 V (Min) - TIP121, TIP126  
 = 100 V (Min) - TIP122, TIP127
- \* Collector-Emitter Saturation Voltage  
 $V_{CE(sat)}$  = 2.0 V (Max.) @  $I_C = 3.0$  A
- \* Monolithic Construction with Built-in Base-Emitter Shunt Resistor

NPN	PNP
TIP120	TIP125
TIP121	TIP126
TIP122	TIP127

5.0 AMPERE  
 DARLINGTON  
 COMPLEMENTARY SILICON  
 POWER TRANSISTORS  
 60-100 VOLTS  
 65 WATTS

### MAXIMUM RATINGS

Characteristic	Symbol	TIP120 TIP125	TIP121 TIP126	TIP122 TIP127	Unit
Collector-Emitter Voltage	$V_{CEO}$	60	80	100	V
Collector-Base Voltage	$V_{CBO}$	60	80	100	V
Emitter-Base Voltage	$V_{EBO}$	5.0			V
Collector Current-Continuous -Peak	$I_C$ $I_{CM}$	5.0 8.0			A
Base Current	$I_B$	120			mA
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	65 0.52			W W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{STG}$	- 65 to +150			$^\circ\text{C}$



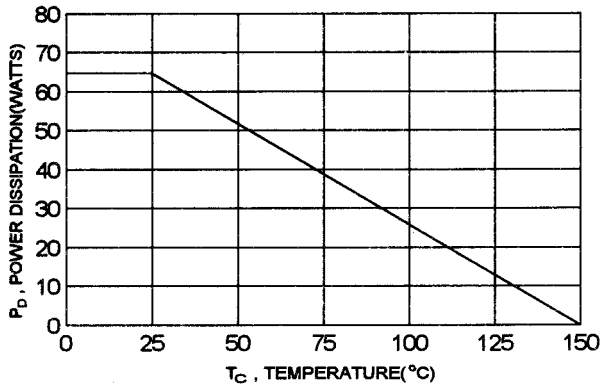
PIN 1.BASE  
 2.COLLECTOR  
 3.EMITTER  
 4.COLLECTOR(CASE)

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance Junction to Case	$R_{\theta jc}$	1.92	$^\circ\text{C/W}$

DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.31
B	9.78	10.42
C	5.01	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	3.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.97
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

FIGURE -1 POWER DERATING



TIP120, TIP121, TIP122 NPN / TIP125, TIP126, TIP127 PNP

**ELECTRICAL CHARACTERISTICS** (  $T_c = 25^\circ\text{C}$  unless otherwise noted )

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector - Emitter Sustaining Voltage (1) ( $I_C = 30\text{ mA}$ , $I_B = 0$ )	$V_{CE(sus)}$	60 80 100		V
Collector Cutoff Current ( $V_{CE} = 30\text{ V}$ , $I_B = 0$ ) ( $V_{CE} = 40\text{ V}$ , $I_B = 0$ ) ( $V_{CE} = 50\text{ V}$ , $I_B = 0$ )	$I_{CEO}$		0.5 0.5 0.5	mA
Collector Cutoff Current ( $V_{CB} = 60\text{ V}$ , $I_E = 0$ ) ( $V_{CB} = 80\text{ V}$ , $I_E = 0$ ) ( $V_{CB} = 100\text{ V}$ , $I_E = 0$ )	$I_{CBO}$		0.2 0.2 0.2	mA
Emitter Cutoff Current ( $V_{EB} = 5.0\text{ V}$ , $I_C = 0$ )	$I_{EBO}$		2.0	mA

**ON CHARACTERISTICS (1)**

DC Current Gain ( $I_C = 0.5\text{ A}$ , $V_{CE} = 3.0\text{ V}$ ) ( $I_C = 3.0\text{ A}$ , $V_{CE} = 3.0\text{ V}$ )	hFE	1000 1000		
Collector-Emitter Saturation Voltage ( $I_C = 3.0\text{ A}$ , $I_B = 12\text{ mA}$ ) ( $I_C = 5.0\text{ A}$ , $I_B = 20\text{ mA}$ )	$V_{CE(sat)}$		2.0 4.0	V
Base-Emitter On Voltage ( $I_C = 3.0\text{ A}$ , $V_{CE} = 3.0\text{ V}$ )	$V_{BE(on)}$		2.5	V

**DYNAMIC CHARACTERISTICS**

Small-Signal Current Gain ( $I_C = 3.0\text{ A}$ , $V_{CE} = 4.0\text{ V}$ , $f = 1.0\text{ MHz}$ )	$h_{fe}$	4.0		
Output Capacitance ( $V_{CB} = 10\text{ V}$ , $I_E = 0$ , $f = 0.1\text{ MHz}$ )	$C_{ob}$		300 250	pF

(1) Pulse Test: Pulse width = 300 us , Duty Cycle  $\leq$  2.0%

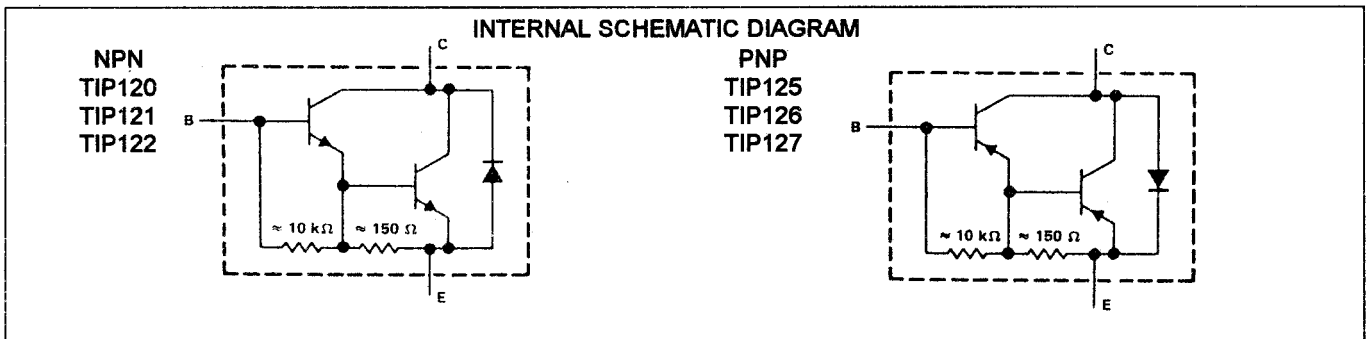


FIG-2 SWITCHING TIME

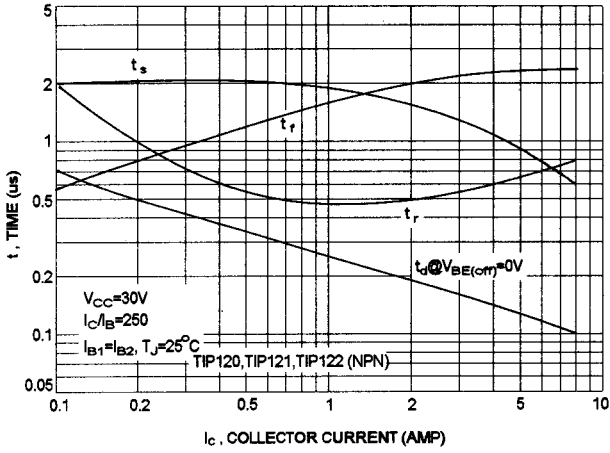


FIG-3 SWITCHING TIME

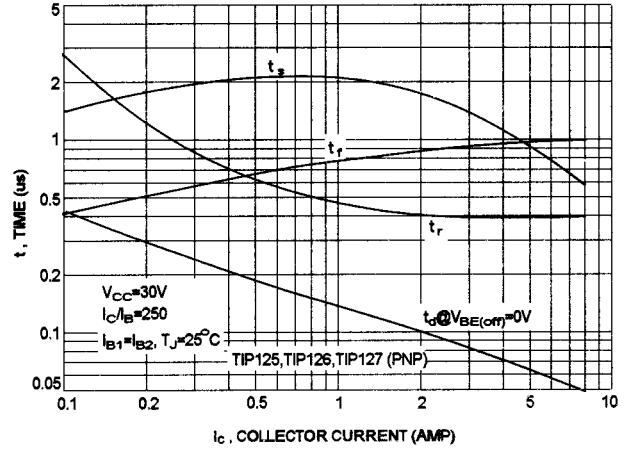


FIG-4 SMALL-SIGNAL CURRENT GAIN

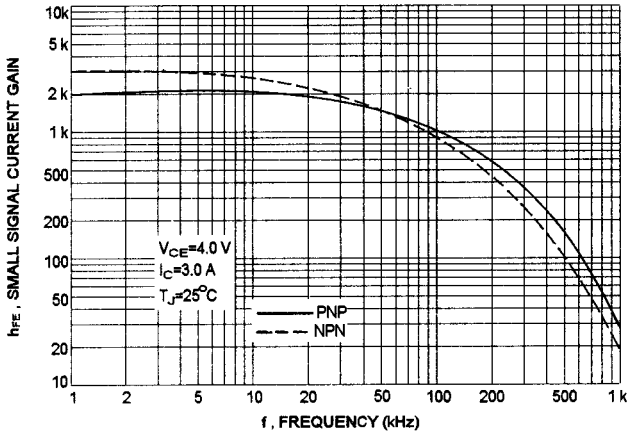


FIG-5 CAPACITANCES

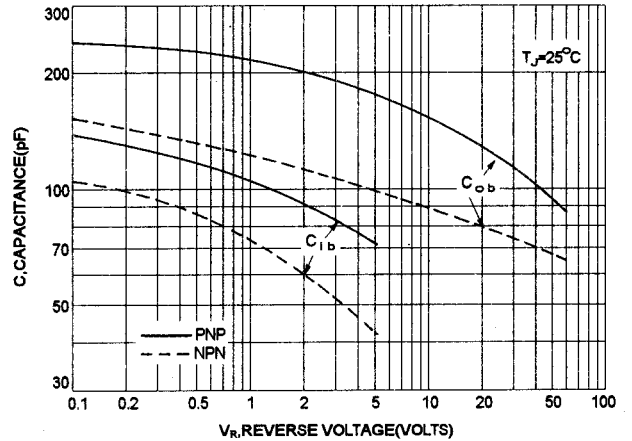
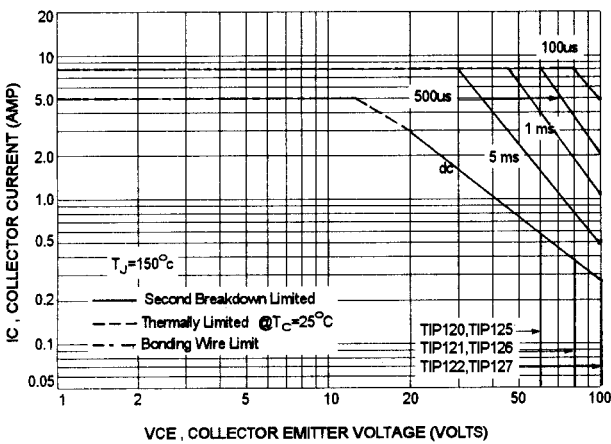


FIG-6 ACTIVE REGION SAFE OPERATING AREA



There are two limitation on the power handling ability of a transistor: average junction temperature and second breakdown safe operating area curves indicate I<sub>C</sub>-V<sub>CE</sub> limits of the transistor that must be observed for reliable operation i.e., the transistor must not be subjected to greater dissipation than curves indicate.

The data of FIG-6 is base on T<sub>J(PK)</sub>=150 °C, T<sub>C</sub> is variable depending on power level. second breakdown pulse limits are valid for duty cycles to 10% provided T<sub>J(PK)</sub> ≤ 150°C. At high case temperatures, thermal limitation will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

TIP120, TIP121, TIP122 NPN / TIP125, TIP126 TIP127 PNP

NPN TIP120,TIP121,TIP122

PNP TIP125,TIP126,TIP127

FIG-7 DC CURRENT GAIN

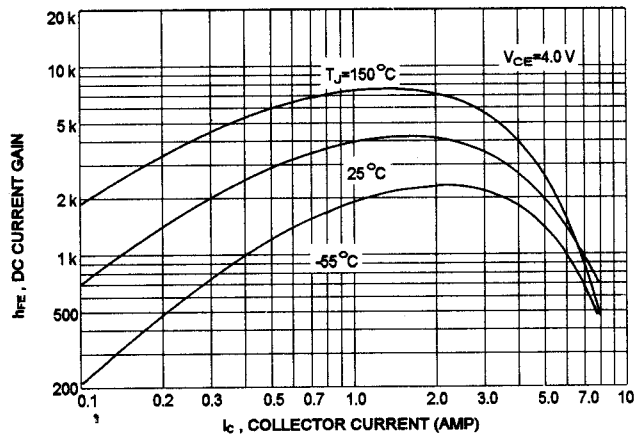
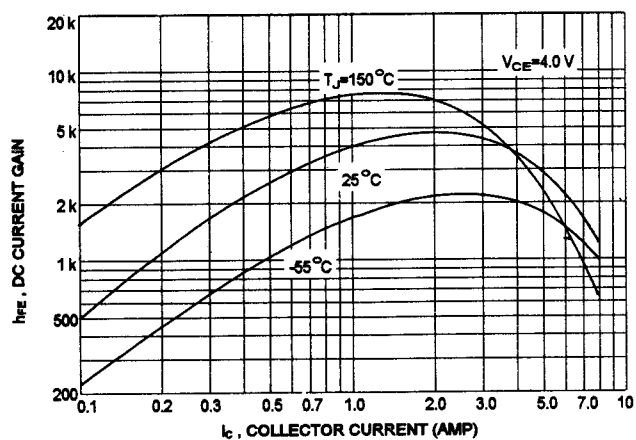


FIG-8 COLLECTOR SATURATION REGION

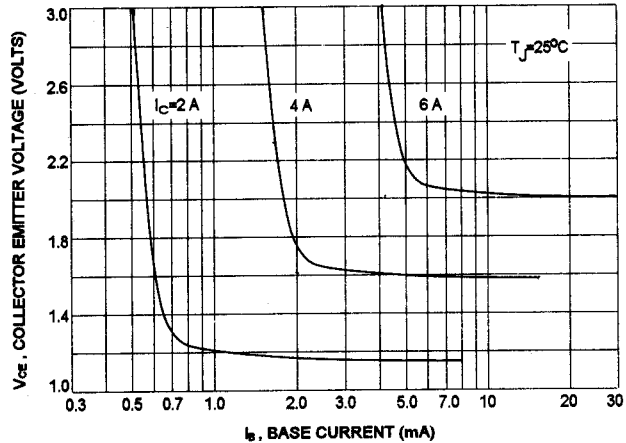
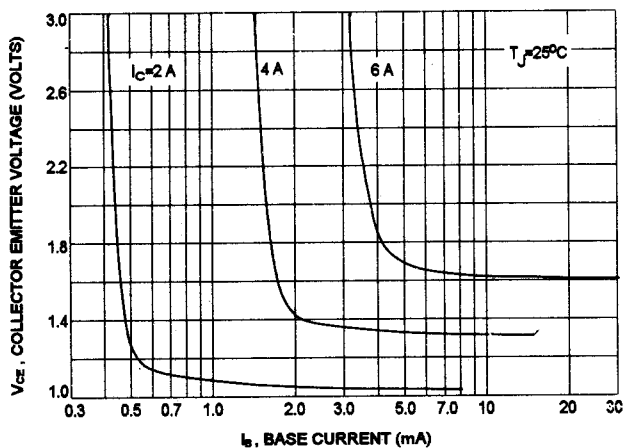


FIG-9 "ON" VOLTAGES

